

1.5V Drive Pch MOSFET

RW1A025AP

● Structure

Silicon P-channel MOSFET

● Features

- 1) Low On-resistance.
- 2) Small high power package.
- 3) Low voltage drive.(1.5V)

● Application

Switching

● Packaging specifications

Type	Package	Taping
	Code	T2CR
	Basic ordering unit (pieces)	8000
RW1A025AP		○

● Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Drain-source voltage		V_{DSS}	-12	V
Gate-source voltage		V_{GSS}	0 to -8	V
Drain current	Continuous	I_D	±2.5	A
	Pulsed	I_{DP} *1	±7.5	A
Source current (Body Diode)	Continuous	I_S	-0.5	A
	Pulsed	I_{SP} *1	-7.5	A
Power dissipation		P_D *2	0.7	W
Channel temperature		T_{ch}	150	°C
Range of storage temperature		T_{stg}	-55 to +150	°C

 *1 $P_w \leq 10\mu s$, Duty cycle $\leq 1\%$

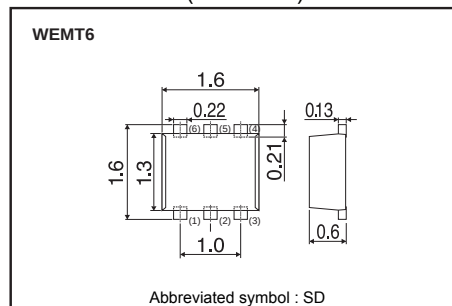
*2 Mounted on a ceramic board.

● Thermal resistance

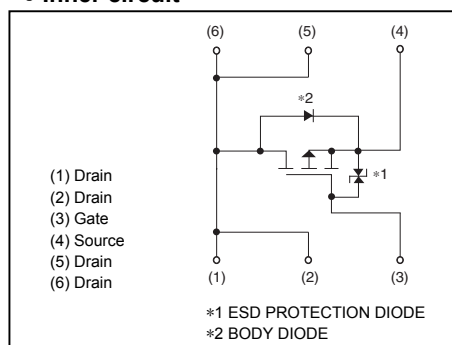
Parameter	Symbol	Limits	Unit
Channel to Ambient	$R_{th}(ch-a)^*$	179	°C / W

*Mounted on a ceramic board.

● Dimensions (Unit : mm)



● Inner circuit



● Electrical characteristics (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Gate-source leakage	I_{GSS}	-	-	-10	μA	$V_{GS} = -8V, V_{DS} = 0V$
Drain-source breakdown voltage	$V_{(BR)DSS}$	-12	-	-	V	$I_D = -1mA, V_{GS} = 0V$
Zero gate voltage drain current	I_{DSS}	-	-	-10	μA	$V_{DS} = -12V, V_{GS} = 0V$
Gate threshold voltage	$V_{GS(th)}$	-0.3	-	-1.0	V	$V_{DS} = -6V, I_D = -1mA$
Static drain-source on-state resistance	$R_{DS(on)}^*$	-	44	62	m Ω	$I_D = -2.5A, V_{GS} = -4.5V$
		-	55	77		$I_D = -1.2A, V_{GS} = -2.5V$
		-	75	110		$I_D = -1.2A, V_{GS} = -1.8V$
		-	90	180		$I_D = -0.5A, V_{GS} = -1.5V$
Forward transfer admittance	$ Y_{fs} ^*$	3.5	-	-	S	$I_D = -2.5A, V_{DS} = -6V$
Input capacitance	C_{iss}	-	2000	-	pF	$V_{DS} = -6V$
Output capacitance	C_{oss}	-	130	-	pF	$V_{GS} = 0V$
Reverse transfer capacitance	C_{rss}	-	120	-	pF	$f = 1MHz$
Turn-on delay time	$t_{d(on)}^*$	-	11	-	ns	$I_D = -1.2A, V_{DD} = -6V$
Rise time	t_r^*	-	40	-	ns	$V_{GS} = -4.5V$
Turn-off delay time	$t_{d(off)}^*$	-	160	-	ns	$R_L = 5\Omega$
Fall time	t_f^*	-	60	-	ns	$R_G = 10\Omega$
Total gate charge	Q_g^*	-	16	-	nC	$I_D = -2.5A$
Gate-source charge	Q_{gs}^*	-	2.4	-	nC	$V_{DD} = -6V$
Gate-drain charge	Q_{gd}^*	-	2.2	-	nC	$V_{GS} = -4.5V$

*Pulsed

● Body diode characteristics (Source-Drain) (Ta = 25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Forward Voltage	V_{SD}^*	-	-	-1.2	V	$I_s = -2.5A, V_{GS} = 0V$

*Pulsed

●Electrical characteristic curves (Ta=25°C)

Fig.1 Typical output characteristics(I)

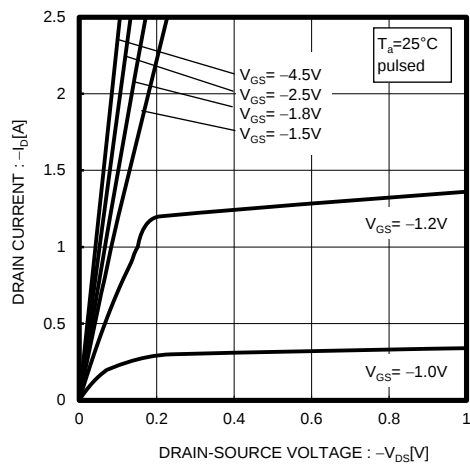


Fig.2 Typical output characteristics(II)

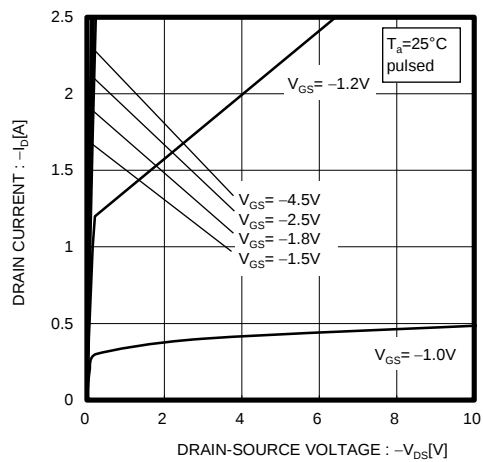


Fig.3 Typical Transfer Characteristics

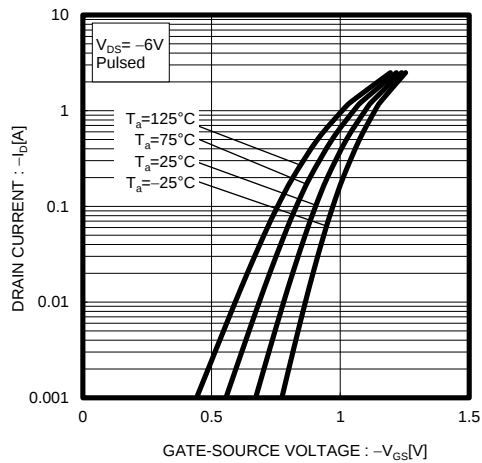


Fig.4 Static Drain-Source On-State Resistance vs. Drain Current (I)

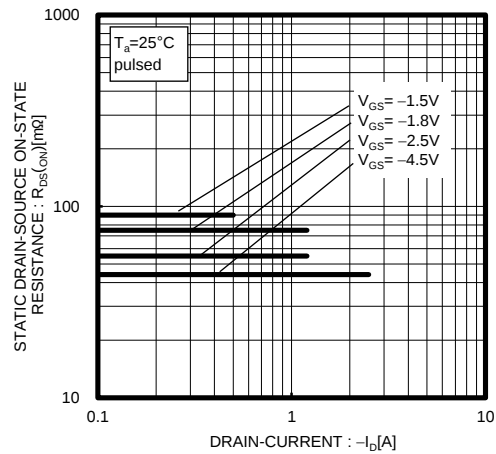


Fig.5 Static Drain-Source On-State Resistance vs. Drain Current(II)

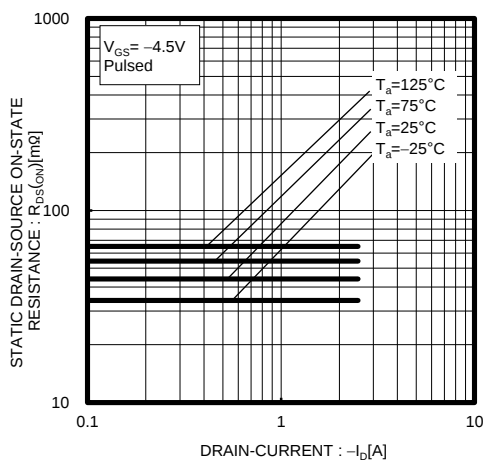


Fig.6 Static Drain-Source On-State Resistance vs. Drain Current(III)

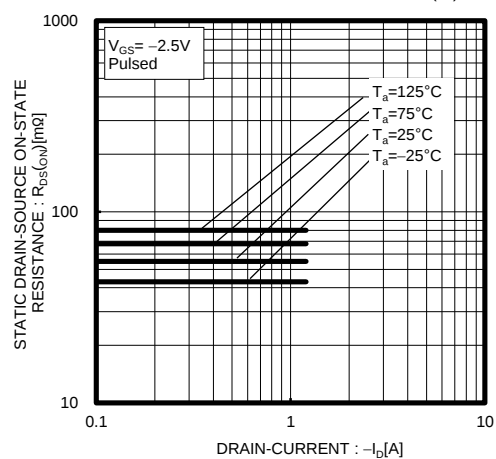


Fig.7 Static Drain-Source On-State Resistance vs. Drain Current (IV)

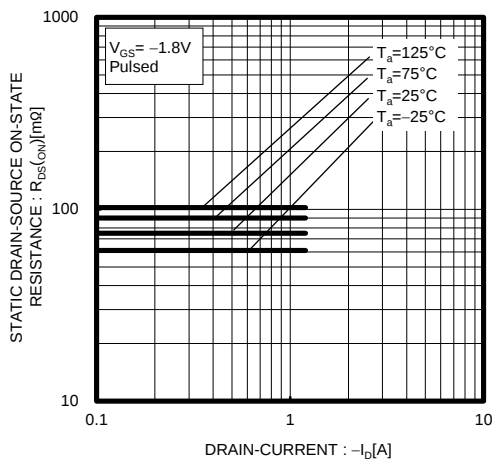


Fig.8 Static Drain-Source On-State Resistance vs. Drain Current (V)

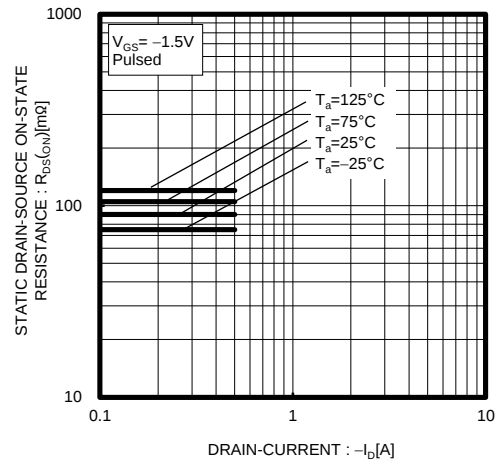


Fig.9 Forward Transfer Admittance vs. Drain Current

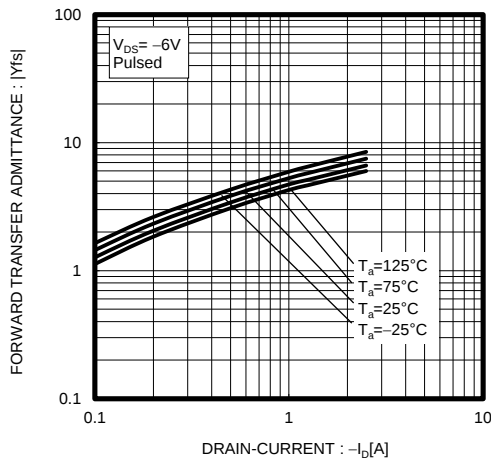


Fig.10 Reverse Drain Current vs. Source-Drain Voltage

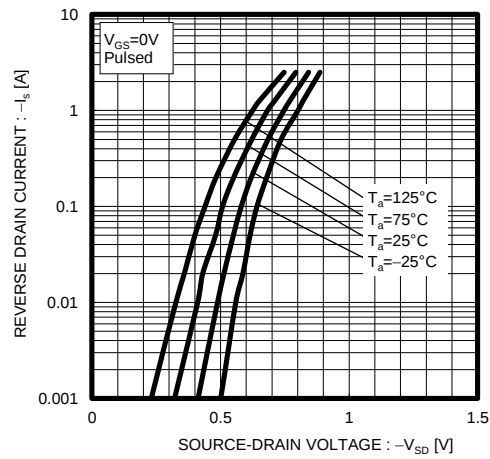


Fig.11 Static Drain-Source On-State Resistance vs. Gate Source Voltage

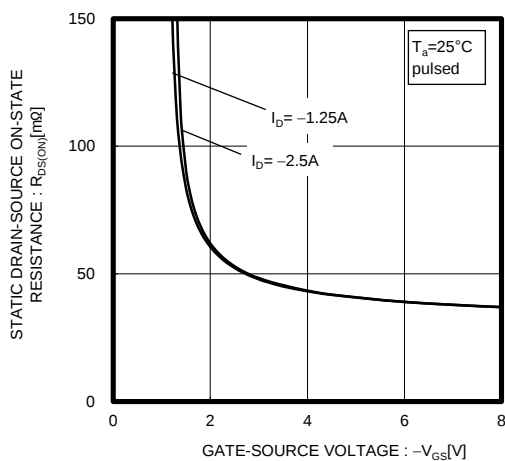


Fig.12 Switching Characteristics

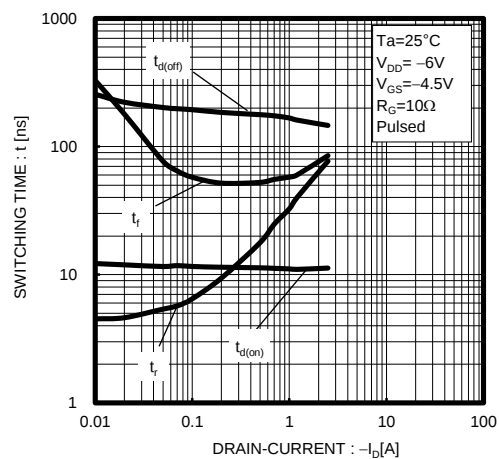


Fig.12 Dynamic Input Characteristics

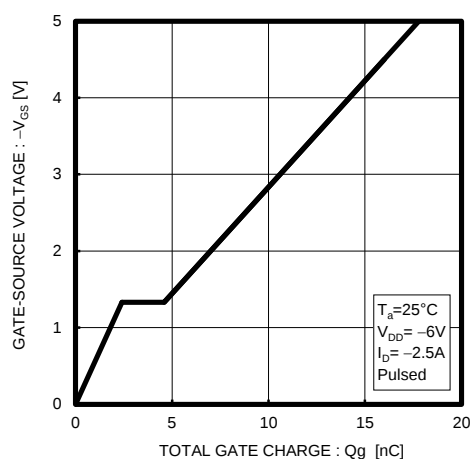
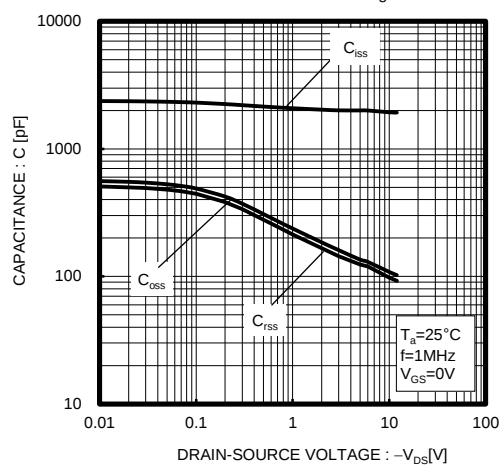


Fig.13 Typical Capacitance vs. Drain-Source Voltage



● Measurement circuits

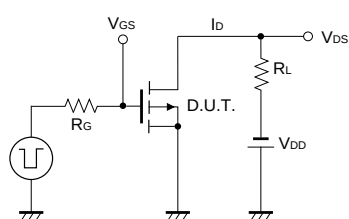


Fig.1-1 Switching Time Measurement Circuit

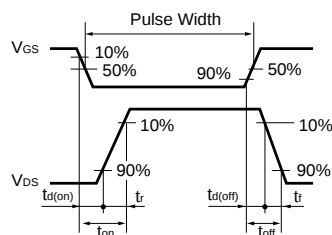


Fig.1-2 Switching Waveforms

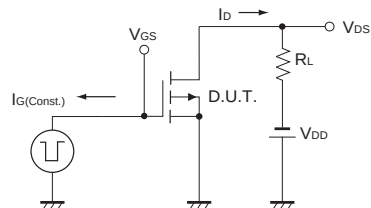


Fig.2-1 Gate Charge Measurement Circuit

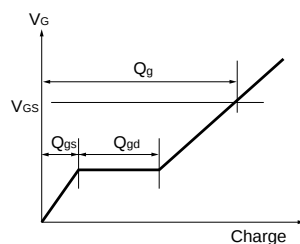


Fig.2-2 Gate Charge Waveform

● Notice

This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

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